BZU-ECE ENEE2360



ENEE236 - Analog Electronics

Course Objectives

- Study diode construction, basic operating principles and modeling.
- To analyze and design diode based circuits used in different application such as ac-dc rectifiers, limiting and clamping, voltage multiplication.
- To Study zener diode operation and usage as voltage regulator.
- To Study construction, operation, biasing of Bipolar Junction Transistors and Field Effect Transistors.
- To design and analyze BJT and FET based amplifier circuits using small signal analysis techniques including their high and low frequency response
- To study operational amplifiers and how to use them in various applications such as amplification, summation, comparison, integration, differentiation
- To study different discrete and integrated circuit Voltage Regulators and be able to design them for different applications

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Course Contents

5. BJT AC Analysis

Amplifiers and small signal analysis, Transistor AC Equivalent Circuits- Hybrid Parameters, Common-Emitter Amplifier; Common-Collector Amplifier; Common-Base Amplifier; Multistage Amplifiers.

6. Field-Effect Transistors (FETs)

The JFET; JFET Characteristics and Parameters; JFET Biasing; The MOSFET Characteristics and Parameters; MOSFET Biasing

7. FET Amplifiers.

FET Amplification; Common-Source Amplifiers; Common- Drain Amplifiers and Common-Gate Amplifiers;

8. Operational Amplifiers and Applications Introduction to Operational Amplifiers; Op-Amp Input Modes and Parameters Negative Feedback; Op-Amps with Negative Feedback ; Comparators; Summing Amplifiers; Integrators and Differentiators. Instrumentation Amplifier; Converters and Other Op-Amp Circuits.



Grading Policy	
Quizes	15%
Projects	15%
Midterm Exam	30%
Final Exam	40%

ENEE236 – Analog Electronics

Introduction to Semiconductors and Semiconductor Diodes

Electronics Circuits

• We encounter electronics in our daily life in form of telephones, radios, television, audio equipment, home appliances, computer and equipment for industrial control and automation .







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The field of electronics deals with the design and application of electronic design .









Semiconductors

Electronic devices as diodes, transistors and integrated circuits are made of semiconductor material.

• Semiconductors : materials whose resistance lies between low resistance of conductor and the high resistance of insulator .

Materials can be classified by their ability to conduct electricity.

1 - Conductors : Materials that easily conduct electrical current

2 – Insulators : Materials that do not conduct electrical current under normal condition

3 – Semiconductors: Material that are between conductors and insulators in their ability to conduct electrical current









Covalent bond in silicon crystals

• At absolute zero degree (-273 C°) all valence electrons are tightly bonded to their atoms and there is no free electrons, so the silicon behave as an



insulator.

Rupture of the a covalent bond

- ► When an electron becomes free that is unattached to any atom, a vacancy is left in the valence band within the crystal . This vacancy is called hole .
- For every free electron, there is one hole.
- ► One broken covalent bond → one free electron + one hole
 - At room temperature there is one broken covalent bond for every 3x10¹² pure Si atoms.



Hole motion When a valence electron moves left to right to fill a hole ٠ while leaving another hole behind, the hole has effectively moved from right to left. (5) A valence electron moves (3) A valence electron moves (1) A free electron into 4th hole and leaves into 2nd hole and leaves leaves hole in a 5th hole. a 3rd hole. valence shell. (4) A valence electron moves 6 A valence electron moves 2 A valence electron moves into 5th hole and leaves into 3rd hole and leaves into 1st hole and leaves a 6th hole. a 4th hole. a 2nd hole. Si











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P-Type Semiconductor

- To increase number of holes in intrinsic silicon, trivalent impurity atoms are added (atoms with three valence electrons) such as boron (B) or gallium (Ga)
- Valence electrons (3) of the impurity atom create covalent bonds with three adjacent atoms of silicon and a fourth electron is missing, creating a hole with each added impurity atom
- Majority carriers in P-type material are holes
- Also there are few free electrons that are created when electron-hole pair are thermally generated, these electrons are minority carriers











First20222023 S-HUB.com Instructor: Nasser Ismail 6) The space occupied between the ion walls is called depletion region.
7) Whenever there exists a positive charge with respect to a negative charge, a voltage difference is set between charges ;(Junction potential, Junction barrier).
8) The junction potential acts as potential barrier that tend to prevent majority carriers from crossing the junction.
9) Minority carriers are aided by the junction potential.











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